

# RJ1P07CBH

## Nch 100V 120A Power MOSFET

V <sub>DSS</sub>	100V
R <sub>DS(on)</sub> (Max.)	5.1mΩ
l <sub>D</sub>	±120A
P <sub>D</sub>	135W

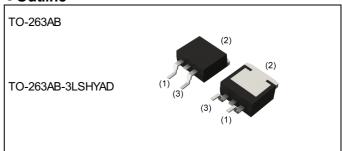
## Features

- 1) Low on resistance
- 2) High power small mold package (TO263AB)
- 3) Pb-free plating; RoHS compliant
- 4) 100% UIS tested

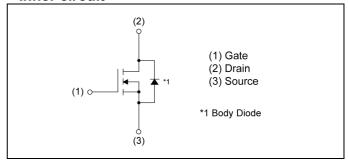
## Application

Switching

## Outline



## •Inner circuit



Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
Type	Tape width (mm)	24
	Quantity (pcs)	800
	Taping code	TL1
	Marking	RJP07CBH

## ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Para	meter	Symbol	Value	Unit
Drain - Source voltage		V <sub>DSS</sub>	100	V
Cartinuous dusin suumant	Silicon limit (V <sub>GS</sub> =10V)	I <sub>D</sub> *1	±120	А
Continuous drain current	T <sub>c</sub> = 25°C (V <sub>GS</sub> =10V)	I <sub>D</sub> *2	±70	А
Pulsed drain current		I <sub>DP</sub> *3	±480	А
Gate - Source voltage		$V_{GSS}$	±20	V
Avalanche current, single pulse		I <sub>AS</sub> *4	33	Α
Avalanche energy, single pulse		E <sub>AS</sub> *4	89	mJ
Power dissipation		P <sub>D</sub> *2	135	W
Junction temperature		T <sub>j</sub>	150	°C
Operating junction and storage temperature range		T <sub>stg</sub>	-55 to +150	°C

## ●Thermal resistance

Parameter	Cumbal	Values			l le:4
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *2	-	-	0.92	°C/W

## ● Electrical characteristics (T<sub>a</sub> = 25°C)

Davamatav	Cymah ol	Symbol Conditions -		Values		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	$\frac{\Delta V_{(BR)DSS}}{\Delta T_i} I_D = 1 \text{mA}$ referenced to 25°C		62.3	-	mV/°C
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 100V, V <sub>GS</sub> = 0V	-	-	5	μA
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$	1	-	±500	nA
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 1mA$	2.0	-	4.0	V
Gate threshold voltage temperature coefficient	$\frac{\Delta  V_{GS(th)}}{\Delta  T_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	-4.5	-	mV/°C
Static drain - source	D *5	V <sub>GS</sub> = 10V, I <sub>D</sub> = 70A	-	3.9	5.1	mO
on - state resistance	R <sub>DS(on)</sub> *5	V <sub>GS</sub> = 6V, I <sub>D</sub> = 35A	-	4.7	7.1	mΩ
Gate resistance	$R_{G}$	-	-	0.9	-	Ω
Forward Transfer Admittance	Y <sub>fs</sub>  *5	V <sub>DS</sub> = 5V, I <sub>D</sub> = 35A	32	-	-	S

<sup>\*1</sup> Limited by silicon chip capability.

<sup>\*2</sup>  $T_c$ =25°C, Limited only by maximum temperature allowed.

<sup>\*3</sup> Pw  $\leq$  10µs, Duty cycle  $\leq$  1%

<sup>\*4</sup> L  $\simeq$  0.1mH, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25 $\Omega$ , Starting T<sub>j</sub> = 25 $^{\circ}$ C Fig.3-1,3-2

<sup>\*5</sup> Pulsed

## ● Electrical characteristics (T<sub>a</sub> = 25°C)

Daramatar	Cymphol	Conditions	Values			Lloit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	4650	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 50V	-	890	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	33	-	
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DD} \simeq 50V, V_{GS} = 10V$	-	40	-	
Rise time	<b>t</b> <sub>r</sub> *5	I <sub>D</sub> = 35A	-	37	-	
Turn - off delay time	t <sub>d(off)</sub> *5	R <sub>L</sub> ≃ 1.42Ω	-	99	-	ns
Fall time	<b>t</b> <sub>f</sub> *5	$R_G = 10\Omega$	-	60	-	

## ● Gate charge characteristics (T<sub>a</sub> = 25°C)

Doromotor	Cymahal	Conditions		Values			11.26	
Parameter	Symbol			Min.	Тур.	Max.	Unit	
Total gate charge	O *5		V <sub>GS</sub> = 10V	-	73.0	-		
Total gate charge	$Q_g^{*5}$	$Q_g$	$V_{DD} \simeq 50V$		-	48.0	-	<b>"</b> C
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 50A	V <sub>GS</sub> = 6V	-	16.4	-	nC	
Gate - Drain charge	Q <sub>gd</sub> *5			-	18.9	-		

## ● Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol Conditions		Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Continuous forward current	I <sub>S</sub> *2		1	-	70	Α
Pulse forward current	I <sub>SP</sub> *3	-	-	-	480	Α
Forward voltage	V <sub>SD</sub> *5	V <sub>GS</sub> = 0V, I <sub>S</sub> = 70A	-	-	1.2	V
Reverse recovery time	t <sub>rr</sub> *5	I <sub>S</sub> = 50A, V <sub>GS</sub> =0V	-	74	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 100A/μs	-	190	-	nC



Fig.1 Power Dissipation Derating Curve

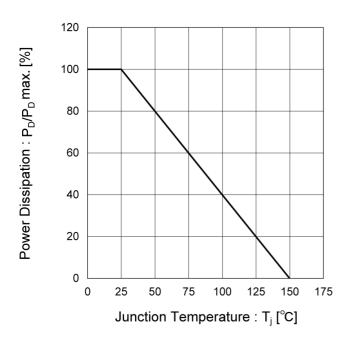
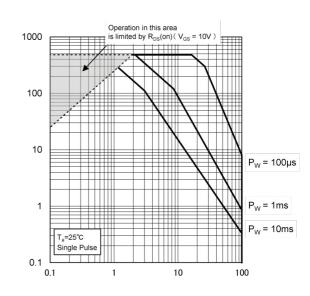


Fig.2 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

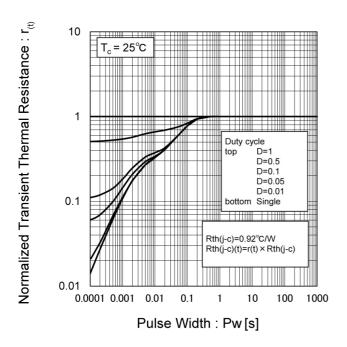


Fig.4 Single Pulse Maximum Power Dissipation

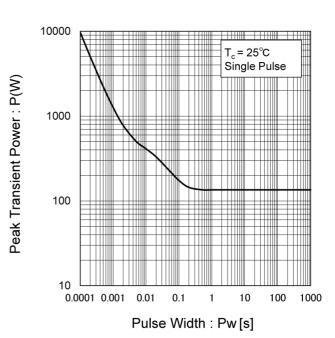


Fig.5 Typical Output Characteristics(I)

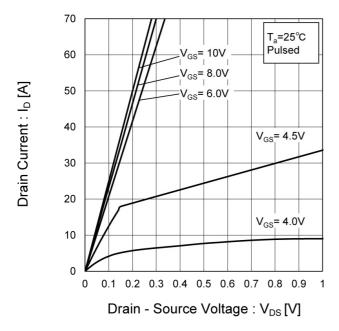
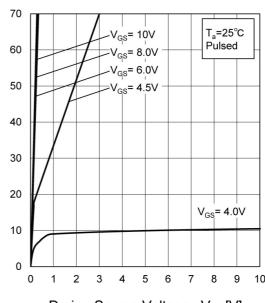


Fig.6 Typical Output Characteristics(II)



Drain Current : I<sub>D</sub> [A]

Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.7 Normalized Breakdown Voltage vs. Junction Temperature

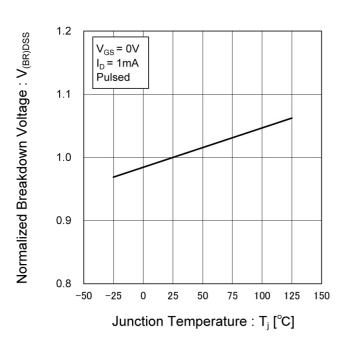
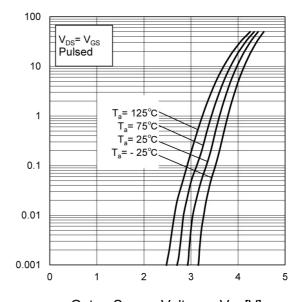


Fig.8 Typical Transfer Characteristics



Gate - Source Voltage :  $V_{GS}[V]$ 

Drain Current : I<sub>D</sub> [A]

Fig.9 Gate Threshold Voltage vs.
Junction Temperature

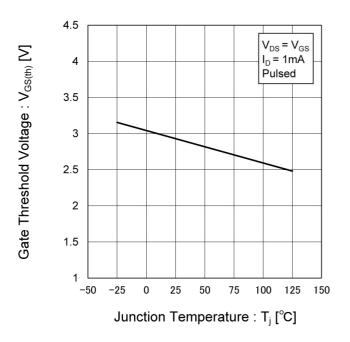


Fig.10 Forward Transfer Admittance vs.
Drain Current

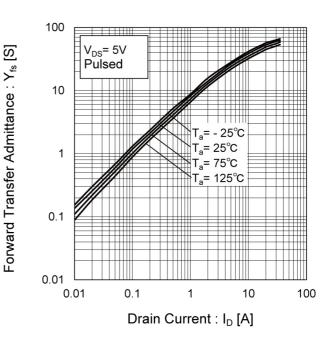


Fig.11 Drain Current Derating Curve

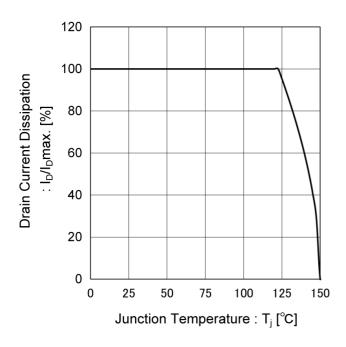


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

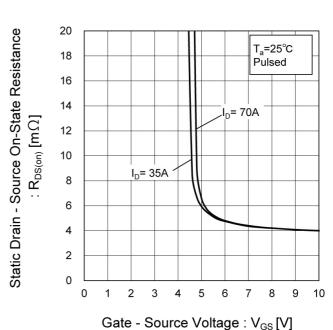


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

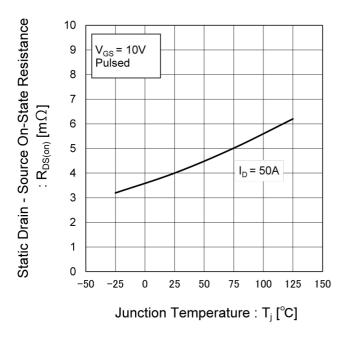


Fig.14 Static Drain - Source On - State
Resistance vs. Drain Current (I)

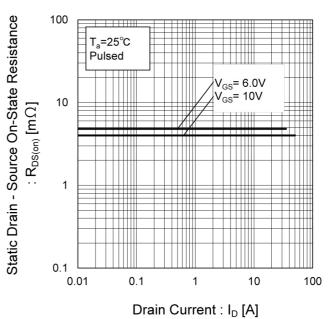


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

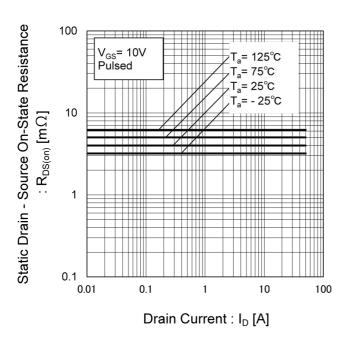


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)

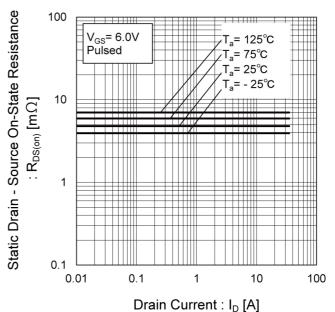
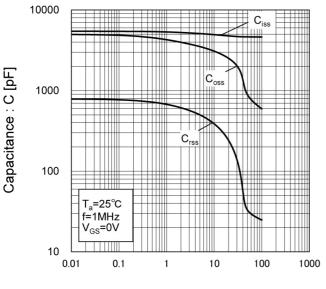
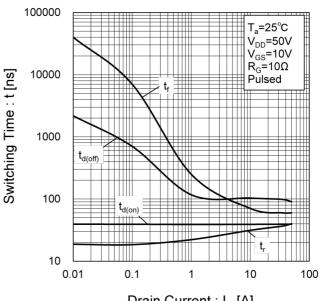


Fig.17 Typical Capacitances vs. Drain - Source Voltage



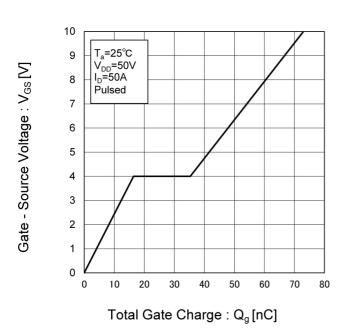
Drain - Source Voltage: V<sub>DS</sub> [V]

Fig.18 Switching Characteristics



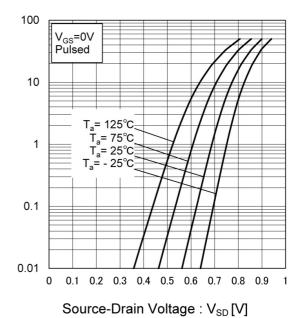
Drain Current: I<sub>D</sub> [A]

Fig.19 Typical Gate Charge



Source Current : Is [A]

Fig.20 Source Current vs. Source Drain Voltage



## Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

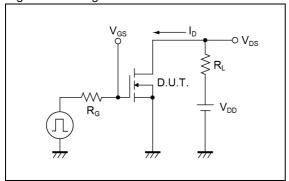


Fig.1-2 Switching Waveforms

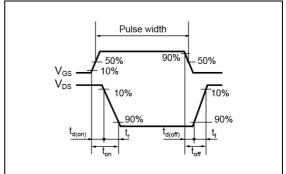


Fig.2-1 Gate Charge Measurement Circuit

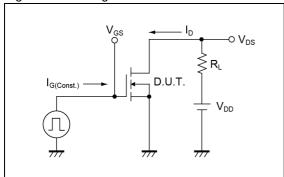


Fig.2-2 Gate Charge Waveform

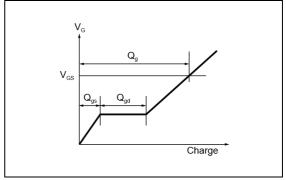


Fig.3-1 Avalanche Measurement Circuit

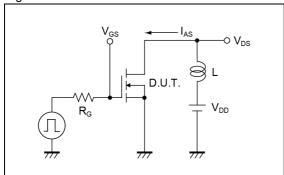
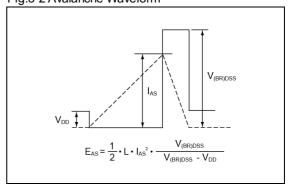
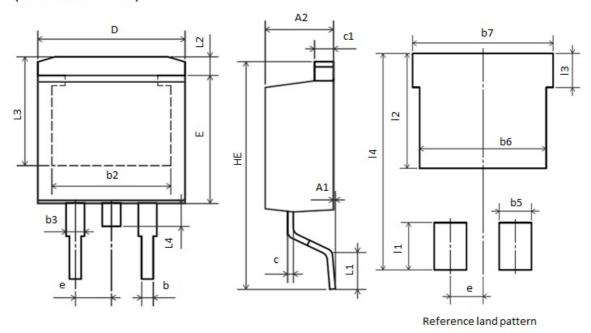


Fig.3-2 Avalanche Waveform



## Dimensions

## TO-263AB (TO-263AB-3LSHYAD)



DIM	MILIM	ETERS	INC	HES
DIN	MIN	MAX	MIN	MAX
A1	0.00	0.25	0.000	0.010
A2	4.37	4.77	0.168	0.188
b	0.70	0.96	0.028	0.038
b2	7.50		0.295	_
b3	1.17	1.47	0.046	0.058
С	0.30	0.53	0.012	0.021
c1	1.22	1.42	0.048	0.056
D	9.86	10.36	0.388	0.408
Е	8.50	8.90	0.335	0.350
е	2.54		0.1	00
HE	14.70	15.50	0.579	0.610
L1	2.00	2.60	0.079	0.102
L2	1.07	1.47	0.042	0.058
L3	6.60	(a <del></del> )	0.260	4.7
L4	1.40	1.70	0.055	0.067

DIM	MILIMETERS	INCHES
DIM	NOM	NOM
1	3.5	0.14
12	8.5	0.33
13	2.5	0.10
4	16.0	0.63
b5	2.5	0.10
ь6	10.0	0.39
ь7	11.0	0.43

Dimension in mm / inches



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CLASSⅢ	CL ACCIII	CLASS II b	CL ACCIII
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

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  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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